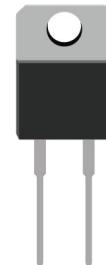


4A, 650V SIC Schottky Rectifier

FEATURES

- 650V schottky rectifier
- Ceramic package provides 2.5KV isolation
- Zero reverse recovery current
- Zero forward recovery voltage
- Switching characteristics independent on temperature
- Positive temperature coefficient of forward voltage
- High temperature soldering guaranteed: 270°C/10 seconds
- RoHS compliant, halogen free

TO-220AC



RoHS
COMPLIANT

HALOGEN
FREE

MECHANICAL DATA

- Case: TO-220AC
- Case material: molding compound meets UL 94V-0 flammability rating
- Polarity: as marked on case



TYPICAL APPLICATION

General purpose use in HAVC,SMPS, AC/DC converters,free wheeling diodes in inverter stages.

MAXIMUM RATINGS

$T_J=25^\circ\text{C}$ unless otherwise noted

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	650	V
Average Forward Rectified Current	I_F	4	A
Repetitive Peak Forward Surge Current (tp=10ms, $T_C=25^\circ\text{C}$)	I_{FRM}	20	A
Peak Forward Surge Current (tp=10ms, $T_C=25^\circ\text{C}$)	I_{FSM}	26	A
Non-Repetitive peak forward surge current (tp = 10 us; $T_C = 25^\circ\text{C}$, pulse)	I_{Fmax}	200	A
Power Dissipation $T_C=25^\circ\text{C}$	P_{tot}	76.5	W
$T_C=110^\circ\text{C}$		33.2	
Operating Junction Temperature Range	T_J	-55 to +175	°C
Storage Temperature Range	T_{STG}	-55 to +175	°C

ELECTRICAL CHARACTERISTICS

$T_J=25^\circ\text{C}$ unless otherwise noted

Parameter	Test Conditions	Symbol	Value		Unit
			Typ.	Max.	
Forward Voltage@ $I_F=4\text{A}$	$T_J=25^\circ\text{C}$	V_F	1.5	1.8	V
	$T_J=175^\circ\text{C}$		1.8	2	
Reverse Current @ V_{RRM}	$T_J=25^\circ\text{C}$	I_R	1	20	μA
	$T_J=175^\circ\text{C}$		12	100	
Total Capacitance	$V_R=0\text{V}, f=1\text{MHz}$	C	185	-	pF
	$V_R=200\text{V}, f=1\text{MHz}$		19	-	
	$V_R=400\text{V}, f=1\text{MHz}$		16.7	-	
Total Capacitance Charge	$V_R=400\text{V}$	Q_C	9.5	-	nC
Capacitance Stored Energy	$V_R=400\text{V}$	E_C	2.4	-	μJ
Thermal Resistance		$R_{\theta JC}$	2.8		°C/W

4A, 650V SiC Schottky Rectifier

RATINGS AND CHARACTERISTIC CURVES

FIG.1: Forward Characteristics

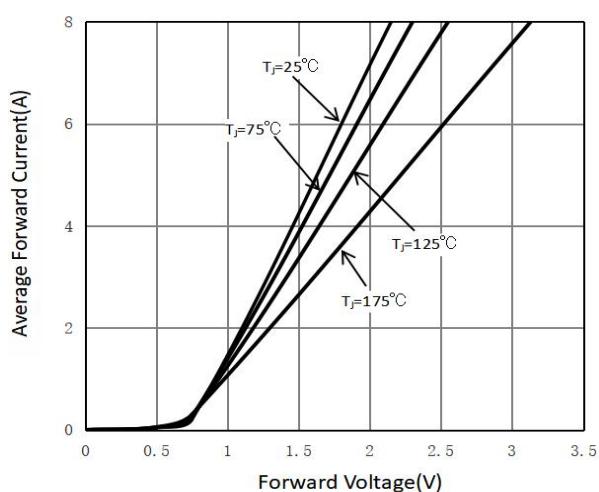


FIG.2: Reverse Characteristics

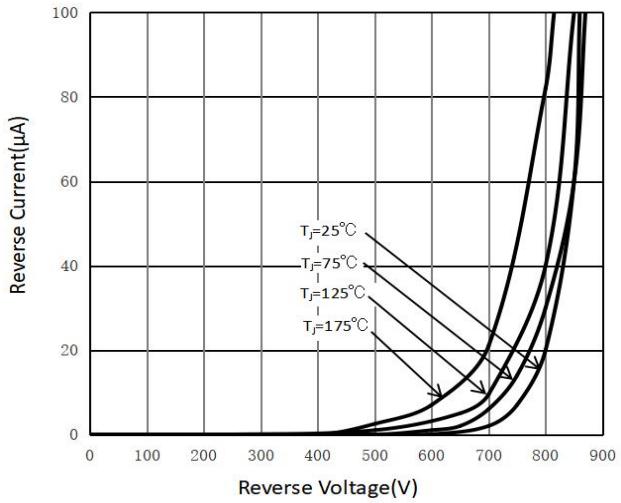


FIG.3: Capacitance Charge vs. Reverse Voltage

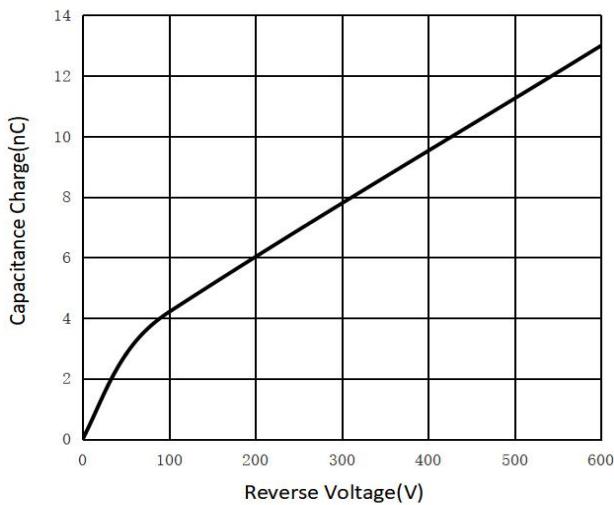


FIG.4: Capacitance Stored Energy

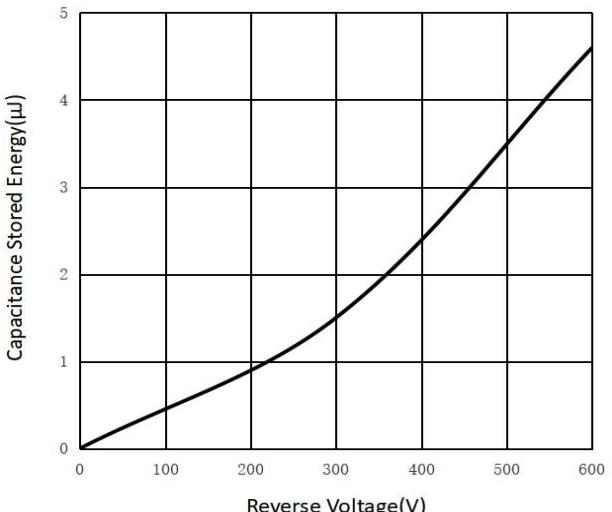


FIG.5: Power Derating

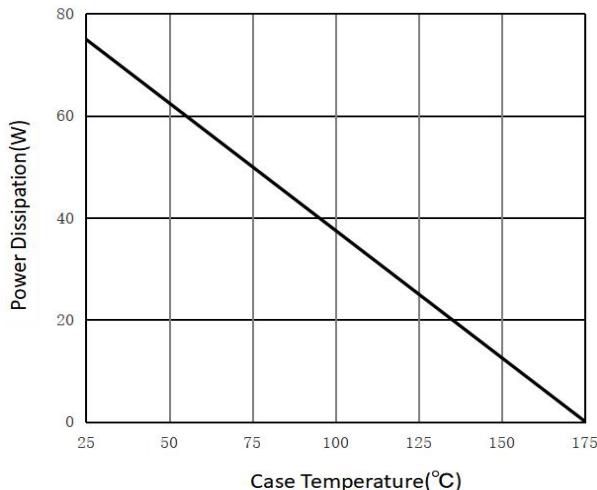
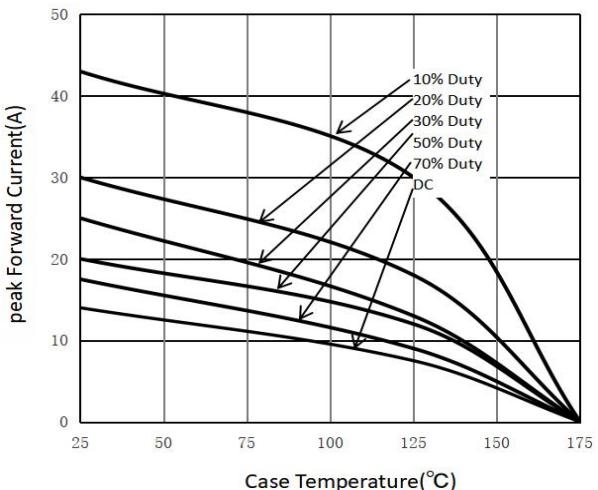
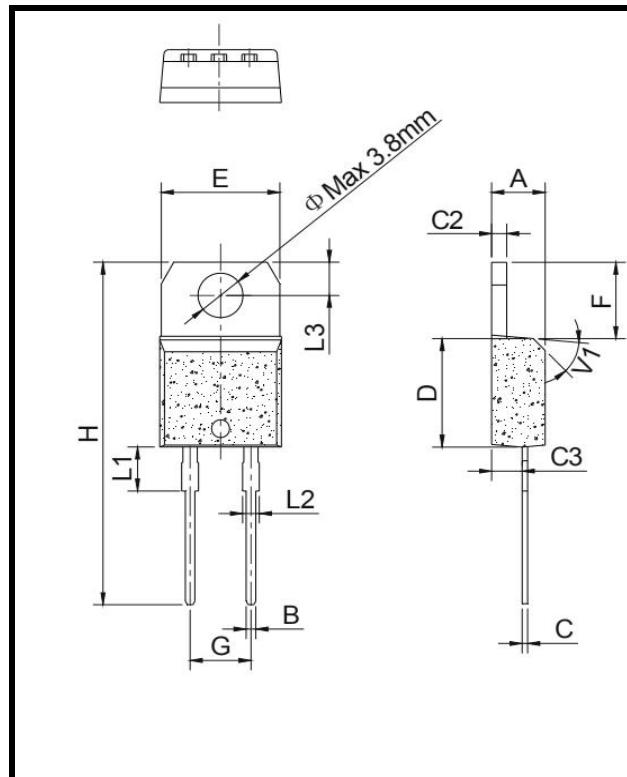


FIG.6: Current Derating



4A, 650V SiC Schottky Rectifier

PACKAGE OUTLINE DIMENSIONS



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.80		10.4	0.386		0.409
F	6.55		6.95	0.258		0.274
G		5.08			0.2	
H	28.0		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

PACKING INFORMATION

Package	Tube(PCS)	Inner Box(PCS)	Carton(PCS)
TO-220AC	50	1,000	8,000